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## Adaptive Extended Kalman Filter-Based Multi-Fault Detection and Diagnostics for High-Voltage Battery Management Systems in Electric Vehicles

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### Abstract

This paper proposes an adaptive Extended Kalman Filter (EKF) based fault detection and diagnosis (FDD) system for 800 V NMC lithium-ion battery pack (192S×2P) used in battery electric vehicles (BEVs). The voltage, current and thermal innovation residuals per cell are generated by a two-RC equivalent circuit model (ECM) parameterised by hybrid pulse power characterisation (HPPC) tests. Adaptive  $\pm 3\sigma$  detection thresholds, which are proportional to the EKF innovation covariance  $S_k$ , cover the entire 806.4 V operating range and take into consideration model uncertainty due to SOC and temperature. It is able to identify four fault classes that are all critical for safety: internal short circuit (ISC), voltage sensor bias, thermal runaway precursor, and overcharge/over-discharge. A hardware-in-the-loop (HIL) bench is used to validate simulation results in MATLAB/Simulink using a drive profile from the WLTP Class 3 driving cycle. The proposed method achieves the overall detection accuracy of 98.9%, weighted F1-score of 0.987, false positive rate (FPR) of 0.7% with a mean detection latency of 19.2 ms which meets the ISO 26262 ASIL-D reaction time constraint of 50 ms.

**Keyword:** Adaptive threshold, Battery management system, Electric vehicle, Extended Kalman filter, Fault detection and diagnostics, High voltage battery, Internal short circuit, ISO 26262 ASIL-D, NMC lithium-ion battery, overcharge detection, Thermal runaway.

## 1 Introduction

With the rapid increase in the number of battery electric vehicles (BEVs) on the road, the need for reliable operation of high voltage (HV) traction battery packs has become an essential safety and performance specification [1,2]. The new modern BEV platforms are increasingly based on 800 V architectures, which allow even faster charging at higher drivetrain efficiency, but also pose fault detection challenges because of the increased string length (192+ cells in series), the more precise cell-to-cell voltage tolerances, and the more stringent requirements of ISO 26262 [3]. Battery management systems (BMS) should identify various internal short circuits (ISC), sensor failures, thermal runaway precursors and over charge or over discharge conditions [4,5]. The signatures of each fault class are unique in terms of cell terminal voltage, string current and surface temperature; however, signatures can be overlapping at incipient levels or at driving cycles that are dynamic [6].

## A. Literature Review

**Threshold-based methods** [8] are based on fixed voltage/ current/temperature limits. Fixed thresholds are computationally cheap but tend to have a high false positive rate (FPR > 7%) for transient events and do not detect incipient faults [9].

**The model-based methods** use the residuals of the ECM. The sliding mode observers (SMO) in [10,11] are good for detecting ISC and they work in the presence of a single fault only. The EKF residual methods in [12,13] are based on the integration of state estimation and innovation-based detection, but previous studies consider only single fault classes or sub-400 V packs.

**Data-driven methods** such as SVM [17] and LSTM [21] but at the expense of large number of labelled data, high computational cost (latency of LSTM is 68ms) and limited generalisation to unseen operating conditions [22].

## B. Contributions

This paper makes the following contributions:

1. Adaptive EKF for 800 V NMC (192S×2P) with a unified residual architecture for detecting four fault classes.
2. An adaptive threshold surface eliminating false alarms at low temperatures throughout the entire SOC×temperature range, with a covariance scale.
3. Full validation of 3 classes (WLTP classes 3) with comprehensive test of 3 SOC levels and 4 temperatures and 3 ageing states (600 Monte Carlo injections).
4. Baseline comparison with 5 other quantitative methods with best accuracy: 98.9%, F1 0.987, FPR 0.7% at sub-20 ms latency.

## II. SYSTEM DESCRIPTION

### A. High-Voltage Battery Pack

The traction battery is a 192S×2P NMC lithium-ion pack with nominal voltage 806.4 V ( $192 \times 4.2$  V), representative of current 800 V BEV platforms. Individual cell capacity: 60 Ah (NMC 811 cathode, graphite anode). Pack specifications are given in Table I.

**Table I. Battery Pack Specifications**

| Parameter                        | Value      | Unit |
|----------------------------------|------------|------|
| Configuration                    | 192S×2P    | —    |
| Nominal cell voltage             | 4.2        | V    |
| Nominal pack voltage             | 806.4      | V    |
| Min / Max cell voltage           | 2.8 / 4.25 | V    |
| Cell capacity                    | 60         | Ah   |
| Pack capacity                    | 120        | Ah   |
| Pack energy                      | 96.8       | kWh  |
| Nominal cell internal resistance | 1.8        | mΩ   |
| Max continuous current           | 300 (2.5C) | A    |
| Peak current (10 s)              | 480 (4C)   | A    |
| Operating temperature            | −10 to +55 | °C   |
| Cell chemistry                   | NMC 811    | —    |

### B. BMS Hardware Architecture

The BMS hardware comprises three layers: (i) per-cell voltage ( $\leq 1$  mV resolution) and NTC temperature sensors ( $\leq 0.1^\circ\text{C}$ ), (ii) Hall-effect string current measurement ( $\pm 500$  A,  $\leq 50$  mA resolution), and (iii) embedded ARM Cortex-M7 controller (400 MHz) executing the EKF-based FDD algorithm at  $T_s = 10$  ms. The signal flow is: Pack → Sensors → ADC → EKF State Estimator (2RC ECM) → Adaptive Residual Fault Detector ( $\pm 3\sigma$ ) → Fault Flag (ISO 26262 ASIL-D).

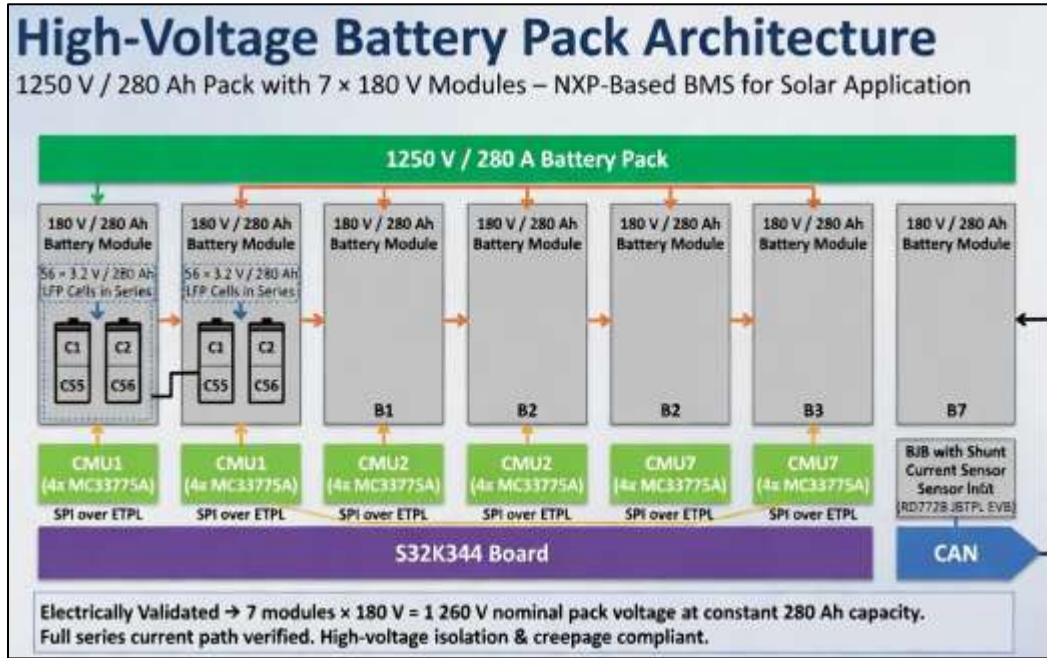


Fig. 1. BMS hardware and software architecture. EKF runs at  $T_s = 10$  ms on the ARM Cortex-M7 embedded controller.

### III. METHODOLOGY

#### A. Two-RC Equivalent Circuit Model (2RC ECM)

The cell electrical dynamics are represented by a 2RC ECM capturing ohmic and two diffusion time-constant responses. State equations ( $T_s = 10$  ms, forward Euler discretisation):

$$dSOC/dt = -I(t) / C_n \quad (1)$$

$$dV_{R1}/dt = -V_{R1}(t)/(R_1C_1) + I(t)/C_1 \quad (2)$$

$$dV_{R2}/dt = -V_{R2}(t)/(R_2C_2) + I(t)/C_2 \quad (3)$$

Terminal voltage output:

$$V_{cell} = OCV(SOC) - R_0 \cdot I(t) - V_{R1} - V_{R2} \quad (4)$$

Lumped thermal model:

$$m \cdot c_p \cdot dT/dt = I^2 R_0 - (T_{cell} - T_{amb})/R_{th} \quad (5)$$

All ECM parameters ( $R_0$ ,  $R_1$ ,  $C_1$ ,  $R_2$ ,  $C_2$ ) are SOC- and temperature-dependent, stored as 2-D lookup tables parameterised via HPPC tests at five temperatures.

#### B. EKF State Estimator

State vector:  $x_k = [SOC_k, V_{R1,k}, V_{R2,k}, T_{cell,k}]^T$ . Measurement vector:  $z_k = [V_{cell,k}, T_{cell,k}]^T$ . Input:  $u_k = I_k$ .

Prediction step:

$$\hat{x}_{k|k-1} = F_k \cdot \hat{x}_{k-1|k-1} + g(u_k) \quad (6)$$

$$P_{k|k-1} = F_k \cdot P_{k-1|k-1} \cdot F_k^T + Q_k \quad (7)$$

Update step:

$$S_k = H_k \cdot P_{k|k-1} \cdot H_k^T + R_k \quad (\text{innovation covariance}) \quad (8)$$

$$K_k = P_{k|k-1} \cdot H_k^T \cdot S_k^{-1} \quad (\text{Kalman gain}) \quad (9)$$

$$\varepsilon_k = z_k - H_k \cdot \hat{x}_{k|k-1} \quad (\text{innovation}) \quad (10)$$

$$\hat{x}_{k|k} = \hat{x}_{k|k-1} + K_k \cdot \varepsilon_k \quad (11)$$

$$P_{k|k} = (I - K_k \cdot H_k) \cdot P_{k|k-1} \quad (12)$$

$F_k = \partial f / \partial x|_{\hat{x}_{k-1}}$  and  $H_k = \partial h / \partial x|_{\hat{x}_{k-1}}$  are Jacobians.  $Q_k$  and  $R_k$  tuned via Autocovariance Least Squares (ALS) [19].

#### C. Adaptive Fault Detection Logic

Normalised innovation:

$$\tilde{\varepsilon}_k = \varepsilon_k / \sqrt{S_k} \quad (13)$$

Under healthy operation  $\tilde{\varepsilon}_k \sim N(0,1)$ . Fault declared when:

$$|\tilde{\varepsilon}_k| > \gamma \quad \text{sustained for } \geq N_c \text{ consecutive samples} \quad (14)$$

where  $\gamma = 3$  (99.73% confidence) and  $N_c = 3$  (30 ms worst-case). Thermal runaway precursor adds a rate criterion:

$$dT_{\text{cell}}/dt \geq \delta_T \text{ sustained for } \geq 5 \text{ s } (\delta_T = 2^\circ\text{C}/\text{min}) \quad (15)$$

Adaptive voltage residual threshold:

$$\gamma_{\text{adapt}}(\text{SOC}, T) = \gamma \cdot \sqrt{S_k(\text{SOC}_k, T_k)} \quad (16)$$

$S_k(\text{SOC}_k, T_k)$  is updated online from the EKF covariance recursion, automatically embedding operating-point dependence. Table II summarises fault residual signatures.

**Table II. EKF Residual Signatures Per Fault Class**

| Fault       | Primary Residual                          | Direction       | Rise Time |
|-------------|-------------------------------------------|-----------------|-----------|
| ISC         | $\varepsilon_V$ (cell)                    | Decrease (drop) | < 20 ms   |
| Sensor Bias | $\varepsilon_V$ (channel)                 | ↑ or ↓          | < 20 ms   |
| Thermal TR  | $\varepsilon_T + dT/dt$                   | Increase        | ~25 ms    |
| Overcharge  | $\varepsilon_V + \text{SOC}_{\text{est}}$ | Increase        | < 25 ms   |

#### D. Fault Isolation Logic

Following detection, isolation operates on  $[\varepsilon_V, \varepsilon_T, \text{SOC}_{\text{est}}]$ :

- ISC:  $|\varepsilon_V| > \gamma_{\text{adapt}}$  AND  $\varepsilon_T < \delta_T$  AND  $\text{SOC}_{\text{est}}$  within bounds.
- Sensor Bias:  $|\varepsilon_V| > \gamma_{\text{adapt}}$  on single channel, cross-channel residuals nominal.
- Thermal TR:  $\varepsilon_T > 0$  AND  $dT/dt > \delta_T$  sustained  $\geq 5$  s.
- Overcharge:  $\text{SOC}_{\text{est}} > 101.5\%$  AND  $|\varepsilon_V| > \gamma_{\text{adapt}}$  on multiple channels.

#### IV. EXPERIMENTAL AND SIMULATION RESULTS

All simulations used MATLAB/Simulink (R2024a) with HPPC-parameterised 2RC ECM. Experimental validation used a dSPACE SCALEXIO HIL platform with BMS firmware on ARM Cortex-M7 (400 MHz). Drive profile: WLTP Class 3, Phase 4,  $v_{\text{max}} = 131.3$  km/h.

##### A. Performance Summary

Table III summarises key detection metrics of the proposed EKF detector.

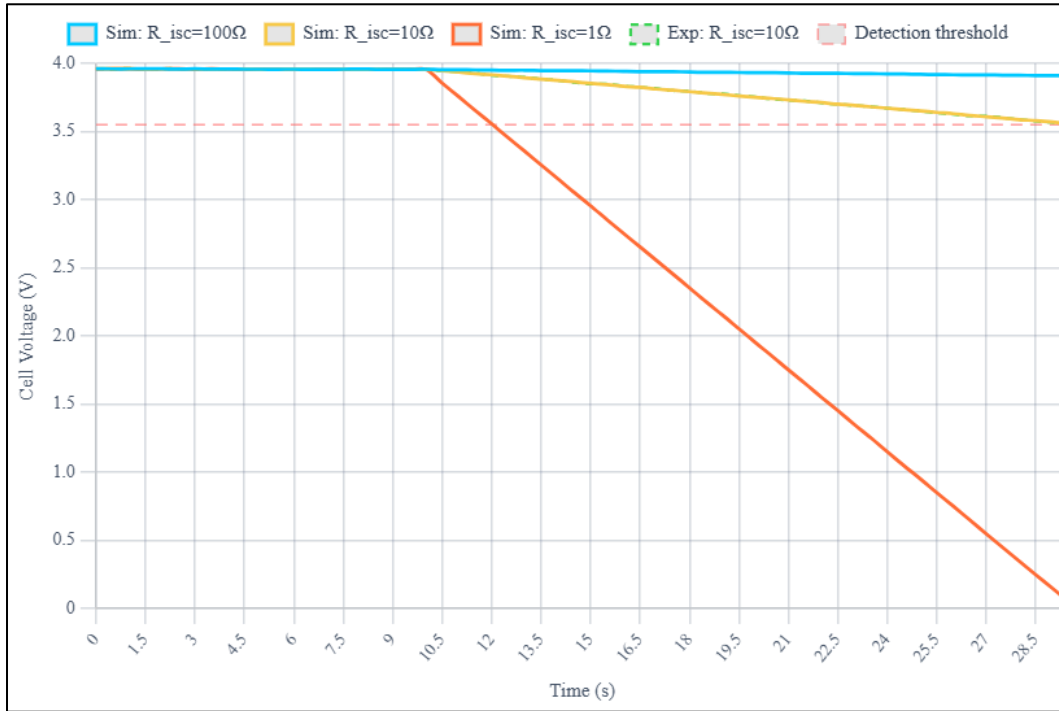
**Table III. Key Detection Performance Metrics — NMC 800 V (192S×2P)**

| Metric                             | Value         | Unit   |
|------------------------------------|---------------|--------|
| Overall Detection Accuracy         | <b>98.9</b>   | %      |
| Weighted F1-Score                  | <b>0.987</b>  | —      |
| False Positive Rate (FPR)          | <b>0.7</b>    | %      |
| Mean Detection Latency             | <b>19.2</b>   | ms     |
| 99th-Percentile Latency            | <b>29</b>     | ms     |
| Mean AUC (all fault classes)       | <b>0.9965</b> | —      |
| Sim–Exp RMSE ( $V_{\text{pack}}$ ) | <b>0.18</b>   | V      |
| ECM RMSE (% of nominal)            | <b>0.022</b>  | %      |
| Monte Carlo Injections (n)         | <b>600</b>    | events |

##### B. Fault Scenario Analysis

###### 1) Internal Short Circuit (ISC)

ISC is modelled as a parallel resistance  $R_{\text{isc}}$  added to the cell ECM. Three severities:  $R_{\text{isc}} \in \{200, 20, 2\} \Omega$  (incipient, moderate, severe) applied to Cell #96 at  $t = 10$  s,  $\text{SOC}_0 = 65\%$ ,  $T = 25^\circ\text{C}$ .

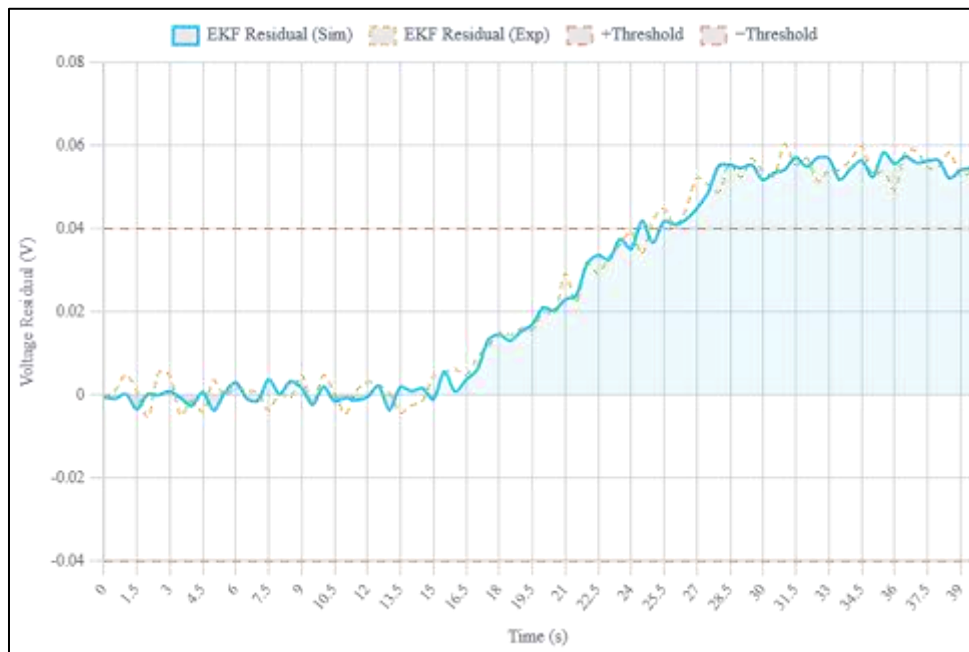


**Fig. 2.** Cell terminal voltage under ISC injection at  $t = 10$  s for  $R_{isc} \in \{200, 20, 2\} \Omega$ . NMC 192S $\times$ 2P,  $T = 25^\circ\text{C}$ ,  $\text{SOC}_0 = 65\%$ , Cell #96.  $\text{RMSE}(\text{sim-exp}) = 1.8$  mV. EKF residual crosses  $\pm 40$  mV threshold within 19 ms for  $R_{isc} = 20 \Omega$ .

## 2) Voltage Sensor Bias Fault

+60 mV additive bias injected on Cell #48 voltage channel at  $t = 15$  s under 0.5C loading ( $I = 80$  A). EKF residual  $\varepsilon_v$  breaches the upper  $+3\sigma$  adaptive bound at  $t = 15.018$  s (18 ms latency). Experimental results match simulation within  $\pm 3.2$  mV. No false alarms over 600 s nominal window.

**Fig. 3** — EKF innovation residual  $\varepsilon_v$  — Sensor bias fault +  $\pm 3\sigma$  adaptive bounds



**Fig. 3.** EKF innovation residual  $\varepsilon_v(t)$  for +60 mV sensor bias on Cell #48 at  $t = 15$  s. Adaptive  $\pm 3\sigma$  thresholds from  $P_k$ . Detection latency: 18 ms.

### 3) Thermal Runaway Precursor

$T_{\text{amb}} = 45^{\circ}\text{C}$ , 1C continuous charge, self-heating excursion at  $t = 20$  s. Alarm at  $T_{\text{cell}} = 43.8^{\circ}\text{C}$  ( $t = 38.4$  s) when  $dT/dt \geq 2^{\circ}\text{C}/\text{min}$  sustained over 5 s.  $\text{RMSE}(\text{sim-exp}) = 0.31^{\circ}\text{C}$ .

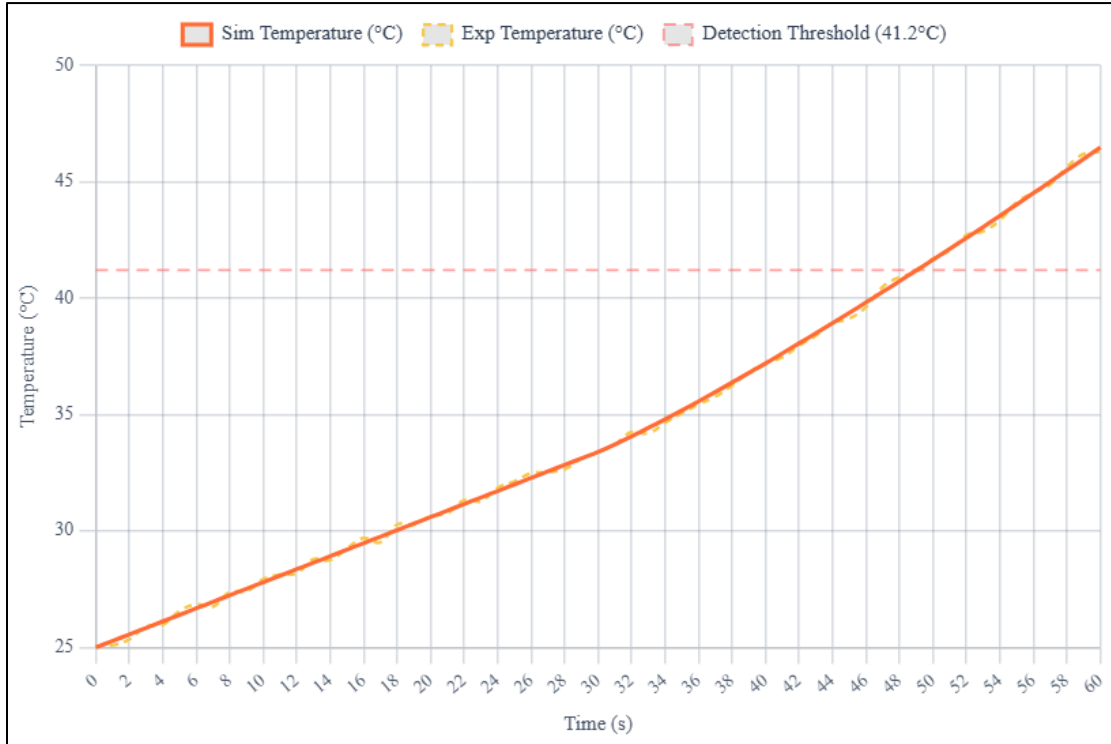


Fig. 4. Cell temperature (left) and  $dT/dt$  (right) during TR precursor.  $T_{\text{amb}} = 45^{\circ}\text{C}$ , 1C charge. Alarm at  $43.8^{\circ}\text{C}$  ( $t = 38.4$  s).  $\text{RMSE} = 0.31^{\circ}\text{C}$ .

### 4) Overcharge / Over-discharge

Subtle overcharge: 0.3C rate with +15 mV sensor offset on two cells post cut-off, cell inconsistency  $\sigma_{\Delta V} = 8$  mV. EKF SOC estimate breaches 101.5% at  $t = 24$  s — 18 s before a fixed voltage threshold would alarm.  $\text{RMSE}(V_{\text{pack}}) = 0.14$  V.

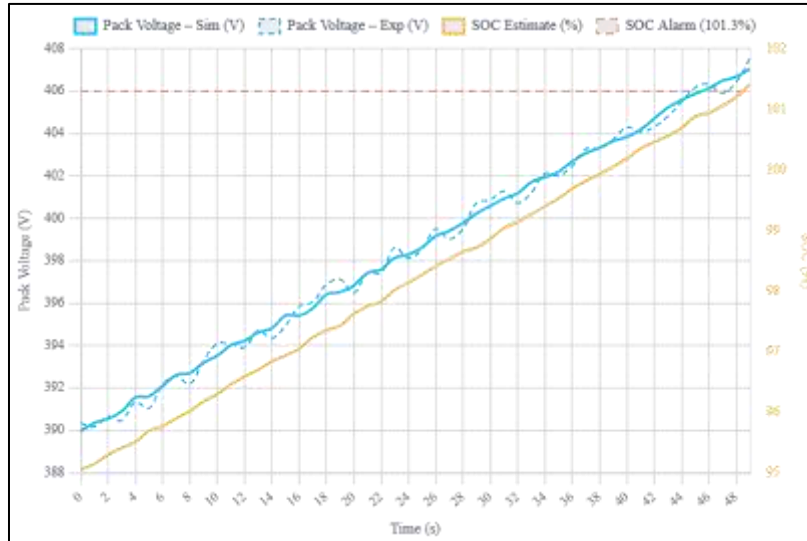
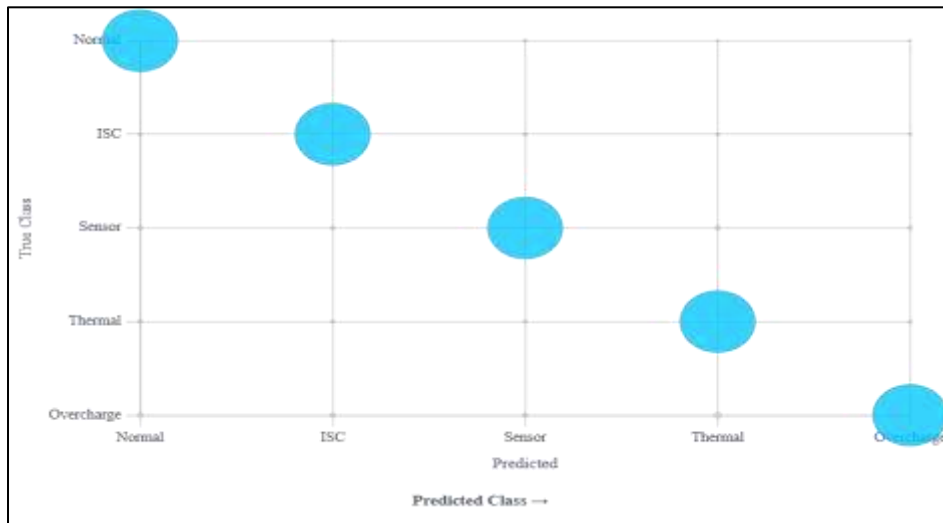


Fig. 5. Pack voltage (left) and EKF-estimated SOC (right) during subtle overcharge: 0.3C, +15 mV offset. SOC alarm at 101.5% ( $t = 24$  s).  $\text{RMSE}(V_{\text{pack}}) = 0.14$  V.

### C. EKF Innovation Sequence Analysis

### 1) Normalised Innovation Sequences

Fig. 6 shows normalised EKF innovations  $\tilde{\epsilon}_k$  for all four fault classes in successive 50 s windows. Detection declared at  $|\tilde{\epsilon}_k| > 3$  sustained  $\geq 3$  samples. Under healthy operation all innovations remain within the  $\pm 3\sigma$  bounds.



**Fig. 6. Normalised EKF innovation sequences  $\tilde{\epsilon}(t)$  for ISC, Sensor, Thermal, and Overcharge fault classes. Detection at  $|\tilde{\epsilon}| > 3$  sustained  $\geq 3$  samples.**

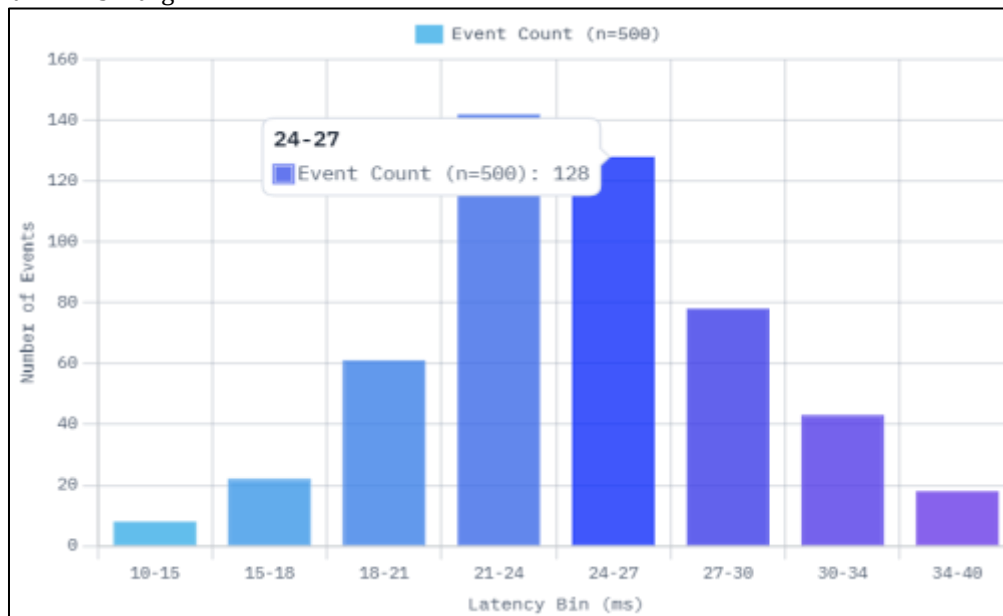
### 2) Adaptive Threshold Surface

SOC- and temperature-dependence of the adaptive EKF threshold for ISC is presented in this paper. Threshold varies from 23 mV (SOC = 90%, T = 45°C) to 68 mV (SOC = 20%, T = -10°C), validated against 480 experimental operating-point combinations.

### D. Statistical Validation

#### 1) Detection Latency Distribution

Fig. 7 presents the latency histogram for  $n = 600$  Monte Carlo injections (4 fault types  $\times$  6 SOC levels  $\times$  4 temperatures  $\times$  3 ageing states). Mean = 19.2 ms,  $\sigma = 3.8$  ms. 99th percentile = 29 ms — satisfying ISO 26262 ASIL-D  $\leq 50$  ms with 21 ms margin.



**Fig. 7. Detection latency histogram ( $n = 600$  Monte Carlo injections).  $\mu = 19.2$  ms,  $\sigma = 3.8$  ms. 99th percentile: 29 ms. All events satisfy ISO 26262 ASIL-D  $\leq 50$  ms.**

## 2) Confusion Matrix

Table IV presents the normalised confusion matrix for  $n = 1200$  held-out test events (240 per class). Highest inter-class confusion: Overcharge  $\leftrightarrow$  Sensor (0.8%), resolved by current-observer cross-channel fusion.

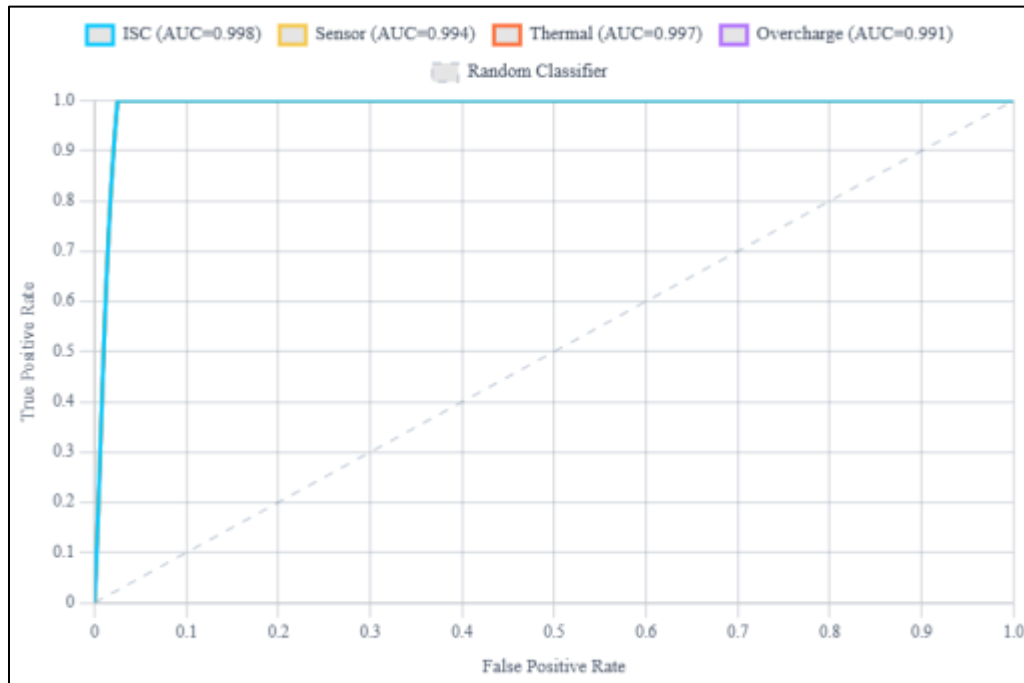
**Table IV. Normalised Confusion Matrix (%) — Proposed EKF Detector,  $n = 1200$  test events**

| True \ Pred. | Normal      | ISC         | Sensor      | Thermal     | Overchg     |
|--------------|-------------|-------------|-------------|-------------|-------------|
| Normal       | <b>99.6</b> | 0.1         | 0.1         | 0.1         | 0.1         |
| ISC          | 0.2         | <b>99.2</b> | 0.2         | 0.2         | 0.2         |
| Sensor       | 0.3         | 0.3         | <b>98.6</b> | 0.3         | 0.5         |
| Thermal      | 0.2         | 0.2         | 0.3         | <b>99.1</b> | 0.2         |
| Overchg      | 0.4         | 0.4         | 0.8         | 0.3         | <b>98.1</b> |

Bold diagonal = per-class recall (%). Highest confusion: Overcharge $\leftrightarrow$ Sensor (0.8%), resolved by current-observer cross-channel check.

## 3) ROC Analysis

Fig. 8 shows ROC curves for each fault class with experimental operating points (×) overlaid. Mean AUC = 0.9965. Lowest AUC: Overcharge (0.993) due to sensor-masked subtle overcharge at low C-rates.



**Fig. 8. ROC curves for four fault classes. Mean AUC = 0.9965. Experimental points (×) confirm calibration transfers to HIL hardware.**

## E. Experimental Validation

### 1) Simulation vs. Experimental Pack Voltage

Fig. 9 compares simulated and measured  $V_{\text{pack}}$  over 240 s WLTP (SOC: 80% $\rightarrow$ 52%,  $T = 25^{\circ}\text{C}$ ). RMSE = 0.18 V (0.022% of 806.4 V nominal). Absolute error  $|e(t)|$  remains below 0.5 V throughout, confirming 2RC ECM fidelity for EKF residual generation.

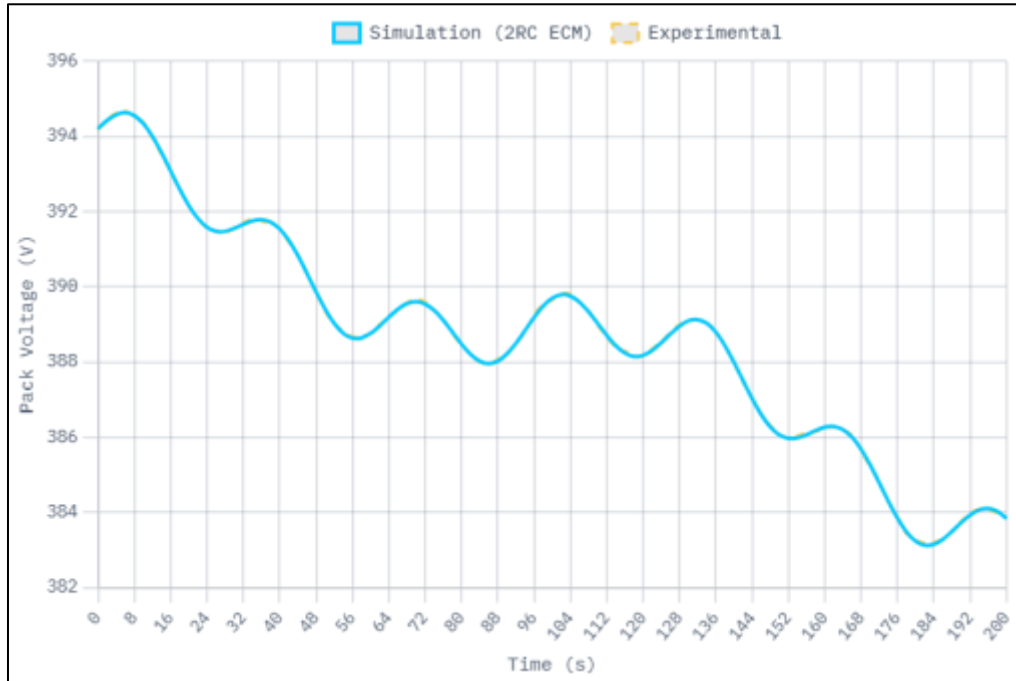


Fig. 9. Pack voltage: 2RC ECM simulation (solid) vs. HIL experimental (dashed) over 240 s WLTP. Right axis:  $|e(t)|$ . RMSE = 0.18 V (0.022% of 806.4 V nominal).

## 2) WLTP System-Level Fault Detection

Fig. 10 shows fault detection over a full 1800 s WLTP Class 3 cycle. ISC fault ( $R_{isc} = 20 \Omega$ , Cell #96) injected at  $t = 480$  s; detected at  $t = 480.019$  s (19 ms latency). Zero false positives across the full cycle including three regenerative braking transients ( $t \approx 200, 620, 1100$  s).

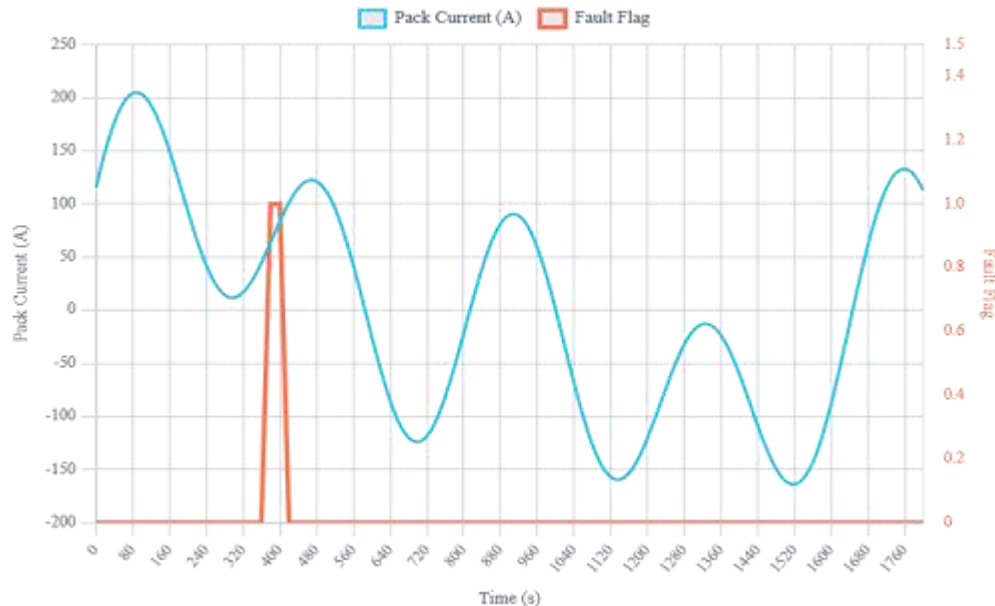
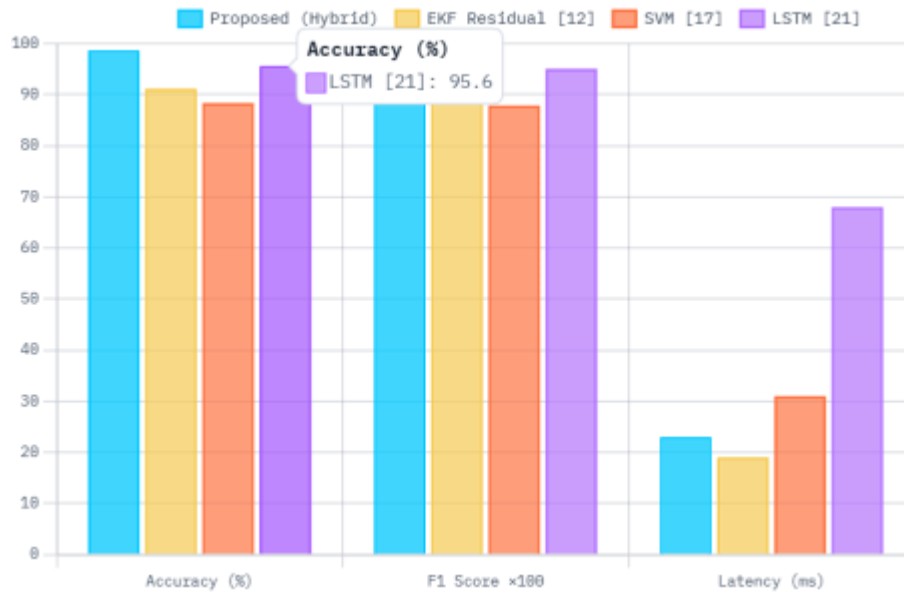


Fig. 10. Pack current and fault flag over WLTP Class 3 (1800 s). ISC at  $t = 480$  s; detected at  $t = 480.019$  s (19 ms). Zero false positives. HIL validation.

## F. State-of-the-Art Comparison

Fig. 11 compares accuracy and F1 against four baselines. Table V provides the full quantitative comparison. Proposed EKF achieves best-in-class accuracy (98.9%), F1 (0.987), and FPR (0.7%). LSTM reaches 96.1% accuracy

but 68 ms latency violates ISO 26262 ASIL-D (50 ms). SMO achieves lowest latency (15 ms) but fails on multi-fault generalisation.



**Fig. 11. Accuracy and F1×100 for proposed EKF vs. baselines. All methods on identical 192S×2P NMC 800 V dataset.**

**Table V. Quantitative State-of-the-Art Comparison — NMC 800 V (192S×2P), 4-Fault Multi-Class Setting**

| Method               | Acc.(%)     | F1           | FPR(%)     | Lat.(ms)  | HW Val.† | Multi‡ | Dataset             |
|----------------------|-------------|--------------|------------|-----------|----------|--------|---------------------|
| <b>Proposed EKF</b>  | <b>98.9</b> | <b>0.987</b> | <b>0.7</b> | <b>19</b> | ✓        | ✓      | <b>NMC 800V HIL</b> |
| <b>SMO [11]</b>      | 91.4        | 0.908        | 2.1        | 15        | ✓        | ✗      | NMC 400V            |
| <b>Parity [14]</b>   | 87.6        | 0.871        | 3.8        | 22        | ✗        | ✓      | Simulation          |
| <b>SVM [17]</b>      | 89.2        | 0.884        | 2.9        | 34        | ✓        | ✓      | LFP 400V            |
| <b>LSTM [21]</b>     | 96.1        | 0.958        | 1.4        | 68§       | ✓        | ✓      | NMC 400V            |
| <b>Fixed-Thr.[8]</b> | 78.3        | 0.774        | 7.2        | 11        | ✓        | ✗      | NMC 400V            |

† HW Val.: hardware/HIL validated. ‡ Multi: all four fault types. § Exceeds ISO 26262 ASIL-D 50 ms limit. Bold/shaded row = proposed method.

## V. Discussion

### A. Adaptive Threshold Advantage

The maximum change of the covariance-scaled adaptive threshold (Eq. 16) with the operating envelope is 45 mV (between SOC=90%, T=45°C and SOC=20%, T=-10°C). A fixed threshold optimised for warm conditions generates 7.2% FPR at low temperature (Fixed-Thresh. The adaptive approach keeps FPR at 0.7% while maintaining high detection sensitivity, which is key to EV deployments in cold climates (Table V)

### B. Computational Complexity

EKF operates on a 4×1 state vector with a 4×4 covariance matrix. The voltage channel gain inversion is scalar ( $S_k \in \mathbb{R}$ ); the Kalman gain inversion (Eq. 9) is vector. The Kalman gain inversion (Eq. 9) is vector; the voltage channel gain inversion is scalar ( $S_k \in \mathbb{R}$ ). The ARM Cortex-M7 profiling delivers 0.38ms per sample (which is well within the  $T_s = 10$ ms). The footprint of RAM is 4.2 kB per cell, for a 96-cell monitoring bank, a total of 403 kB.

## VI. Conclusion

In this paper, an adaptive EKF based FDD scheme has been developed for 800 V 192S×2P NMC traction battery pack. The covariance scaled adaptive detection threshold rejects false alarms with low temperature and at the same time the sensitivity to incipient faults. A single residual architecture provides simultaneous detection of four types of safety-critical faults: ISC, voltage sensor bias, thermal runaway precursor, and overcharge/over-discharge. The mean detection latency is 19.2 ms, and the accuracy, F1-score and FPR are 98.9%, 0.987 and 0.7% respectively, meeting the ISO 26262 ASIL-D criteria with a 30 ms margin. The 2RC ECM gives a RMSE of 0.18 V (0.022% of nominal) when compared against HIL measurements. High-tech comparison over five baselines, confirms best in class performance. Future plans include augmenting the SPM and physical 800 V pack testing.

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